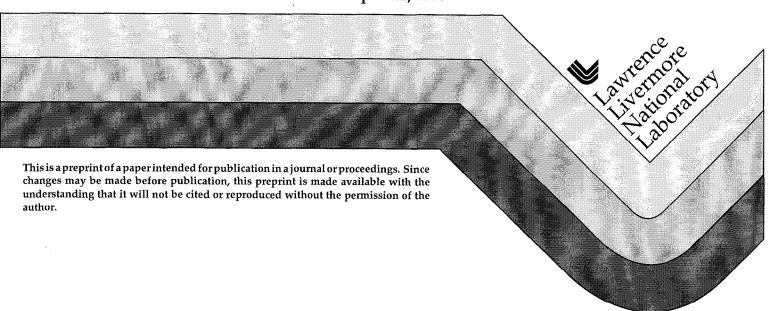
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Abstract: We report room-temperature mid-IR laser operation in a new low-phonon-frequency, non-hygroscopic host crystal CaGa₂S₄ (calcium thiogallate). Laser action at 4.31 μ m on the $^6H_{11/2} \rightarrow ^6H_{13/2}$ transition of trivalent dysprosium was achieved with a slope efficiency of 1.6%.

OCIS codes: (140.3380) Laser materials; (140.3580) Lasers, solid-state; (140.5680) Rare-earth and transition metal solid-state lasers

Introduction

Due to applications such as remote-sensing and IR countermeasures, there has been a great deal of interest in solid-state mid-IR (3-10 μ m) lasers. ^{1,2,3,4} Currently, optical parametric oscillator systems (OPO's) are typically used to cover these wavelengths. They incorporate both non-linear media and pump sources, leading to some complexity and sensitivity in the optical system. These issues could be circumvented with direct light generation in solid-state laser media. To avoid luminescence quenching, hosts for these direct lasers must have maximum phonon frequencies below ~350 cm⁻¹, effectively ruling out traditional oxides and fluorides at longer wavelengths. While room-temperature laser operation has been observed previously in some fluoride hosts beyond

4 μm. 5,6 special efforts had to be taken to overcome the extremely low (< 0.01%) radiative quantum yields of these materials. More success has been achieved for laser operation in rare-earth doped oxide and fluoride hosts between 3 and 4 μm (Dy^{3+ 7,8,9}, Pr^{3+ 10}, Er^{3+ 11,12,13,14} and Ho^{3+ 15,16,17,18}.) Sulfide and chloride hosts have received the most attention for laser action beyond 4 μm because of their lower vibrational frequencies. Laser operation beyond 7 μm has been achieved in LaCl₃, ¹⁹ a low-phonon-energy chloride host that is hygroscopic. Identifying a low-phonon-frequency crystal that incorporates rare-earth ions and resists attack by moisture has been difficult. We report 4.3-4.4 μm lasing on the $^6H_{11/2} \rightarrow ^6H_{13/2}$ transition of Dy³⁺ in crystalline CaGa₂S₄ (see Figure 1), a host that is *not moisture sensitive*. To our knowledge, this is the first report of laser action beyond 4 μm in any rare-earth-doped sulfide. Previous work in CaGa₂S₄ was concerned with phosphor studies. ^{20,21} Spectroscopic data and 1.4 μm laser operation in CaGa₂S₄:Dy³⁺ were reported previously by the present authors. ²²

Crystal growth and physical properties

CaGa₂S₄ is biaxial, belonging to the orthorhombic crystal class (space group Fddd) and possesses a maximum phonon frequency of ~ 350 cm⁻¹. ²³ The 1.5 x 1.2 x 0.7 cm³ sample used in our experiments was cut from a 19 mm-diameter x 100 mm single crystal grown at Sanders by the horizontal gradient freeze technique in a two-zone transparent furnace. ^{24,25} Dy³⁺ was doped on the Ca²⁺ site to an estimated concentration of 8 x 10¹⁹ cm⁻³ (2.0 mol% in the melt and an estimated 60% distribution coefficient). Na⁺ was also added (2 mol%) to maintain charge balance. Two axes of the biaxial indicatrix were

identified at extinction positions in a polariscope. These directions have been labeled 'slow' and 'fast'.

Spectroscopy

In our previous work, 22 spectroscopic data relevant to laser operation such as absorption cross sections, emission cross sections (σ_{em}), and lifetimes (τ_{upper}) were measured for a sample of CaGa₂S₄:Dy³⁺. A Judd-Ofelt analysis yielded radiative lifetimes (τ_{rad}), branching ratios (β), and radiative quantum yields ($\eta = \tau_{upper}/\tau_{rad}$). Table 1 gives these data for the present laser sample. The Dy³⁺ energy level diagram indicating the pump and laser transitions is shown in Figure 1. Figure 2 shows the absorption spectrum, polarized along the 'slow' and 'fast' sample axes described above. Notice that the absorption at 1.32 μ m (the laser pump wavelength) is almost 5 times greater along the 'fast' axis, making it the preferred pump polarization.

Table 1. Spectroscopic data for CaGa₂S₄:Dy³⁺.

Transition	λ (μm)	τ _{upper} (ms)	τ _{rad} (ms)	η (%)	β (%)	$\sigma_{\rm em} = (10^{-20} {\rm cm}^2)$
$^{6}\text{H}_{11/2} \rightarrow ^{6}\text{H}_{13/2}$	4.3	3.02	4.16	73	7	0.7

Experimental setup

The uncoated rectangular almost-parallelepiped sample was placed in the center of a 20 cm confocal cavity and end-pumped at normal incidence by a Nd:YAG laser operating at 1.319 μ m (and 1.338 μ m) with 75 μ s, 1 Hz pulses. To avoid walk-off along the two polarization axes of the sample and maximize absorption, the input beam was polarized

along the 'fast' axis with a calcite polarizer. The pump spot profile was measured by a razor scan and fit to a Gaussian (1/e amplitude) radial spot size of 350 +/-10 μ m. A 1500 nm long-pass filter and 10 cm CaF₂ lens imaged the IR laser light at a 77K InSb detector for temporal waveform acquisition, or to a Molectron J3-09 pyroelectric detector for slope-efficiency measurements. A glass slide pick-off and Molectron J-25 pyroelectric detector measured the input pump energy. The laser output spectra were recorded with a 1-meter, 300 groove/mm grating monochromator located a few meters from the cavity. A calcite polarizer measured the polarization state of the mid-IR output. Although the sample had a 'laser-grade' polish, its end faces were not perfectly parallel. A wedge angle of ~3 mrad was determined by examination of reflections of a single He-Ne laser beam from both end faces of the sample.

4.31 µm laser results

Four cavity mirrors were employed for 4.3 μ m operation with transmissions of 0.84% (high reflector or 'HR'), 0.84%, 2.55%, and 7.65% (output coupler or 'OC'). Data was recorded for three mirror configurations with total transmissions (HR + OC) of 1.68%, 3.39%, and 8.49%. Due to strong fundamental CO₂ absorption (~ 0.0025 cm⁻¹ at 4.3 μ m), the cavity was purged with dry nitrogen for operation near 4.3 μ m. Pump energy was limited by concerns of damage, whose threshold was estimated at ~ 15 J/cm² of absorbed fluence. Absorbed energy is calculated from incident energy via the relation²⁶

$$E_{abs} = E_{inc} (1-R_F)(1-e^{-\alpha l})(1-R_F e^{-\alpha l})^{-1}$$
(1)

where E_{inc} is the laser energy incident on the sample, R_F is the Fresnel reflectivity, α is the absorption coefficient at the pump wavelength, and l is the sample length. Threshold estimates were made using a well-known formula for end-pumped lasers⁶

$$E_{abs}^{th} = \frac{\pi(w_p^2 + w_l^2)}{4\sigma_{em}\eta_p} \frac{hc}{\lambda_p} (L+T)$$
(2)

where w_p is the minimum pump beam radius in the sample, w_l is the laser waist calculated based on cavity parameters, σ_{em} is the emission cross section, η_p is the pumping efficiency (the fraction of absorbed pump photons that populate the upper laser level), L is the round-trip passive loss in the cavity (to be inferred from a Findlay-Clay plot), T is the total transmission (HR + OC), and λ_p is the pump wavelength. Slope efficiency was calculated using the formula²⁷

$$\eta_{\text{slope}} = \eta_p \, \eta_B \, \underline{\lambda}_p \, \underline{T}$$

$$\lambda_l \, (L+T)$$
(3)

where η_B is the pump and laser beam overlap factor, calculated assuming Gaussian beam profiles, and λ_I is the laser wavelength.

Slope efficiency curves are shown in Figure 3 for two of the cavity configurations, and all data are summarized in Table 2, which includes the predicted result values. A Findlay-Clay plot of absorbed energy threshold vs. total transmission is shown in Figure 4, yielding a passive loss of L = 0.9% +/- 0.3%. This low value is perhaps expected if the

scattering losses obey a Rayleigh λ^{-4} dependence and the Fresnel losses imposed by the ~ 3 mrad sample wedge are compensated by the confocal cavity geometry.

Threshold measurements agreed relatively well with calculated thresholds, but slope efficiency measurements were an order of magnitude below the calculated values. The discrepancy has not been resolved. Notice that the slope efficiencies do not vary greatly with the different output coupler reflectivities, as expected when the passive losses L << T. There may be additional losses not compensated by greater output coupling (such as optical aberrations in the sample). AR-coated samples, and samples with better optical quality, planned for future experiments, may perform better.

Table 2. Summary of $CaGa_2S_4:Dy^{3+}$ 4.31 µm laser threshold and slope data. A passive loss value of L = 0.9 % was used to calculate thresholds and slope efficiencies.

Total output coupling (%)	Measured threshold (mJ)	Calculated threshold (mJ)	Measured slope efficiency (%)	Calculated slope efficiency (%)
1.7	1.3	2.1	1.1	12.3
3.4	2.4	3.5	1.6	14.9
8.5	5.2	7.7	1.4	17.0

The laser output and fluorescence emission spectra are shown in Figure 5. The laser output of an unpurged cavity (peak wavelength 4.38 μ m) is also shown in this figure for comparison. The extra loss imposed by the CO₂ absorption (~ 5% per pass for T = 1.7%) forced the laser to operate at a longer wavelength. These data suggest tuning is possible in the range 4.25 –4.70 μ m. The purged-cavity laser spectrum near 4.31 μ m includes the

 CO_2 absorption along the ~ 2 meters of unpurged pathlength between the laser and the monochromator. The laser light was polarized along the 'fast' sample axis.

Conclusions

CaGa $_2$ S $_4$ (calcium thiogallate) has proven to be a viable, non-hygroscopic host material suitable for mid-IR laser operation. We have demonstrated tunable room-temperature laser action around 4.3-4.4 μ m in this low-phonon-energy host. This opens the door for compact, direct solid-state lasers operating in the 2-5 μ m range important for remote sensing and IR countermeasures.

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Figure Captions:

- 1) Energy levels and laser scheme of trivalent dysprosium.
- 2) Polarized absorption spectrum for CaGa₂S₄:Dy³⁺, which is biaxial.
- 3) Slope efficiency curves for $CaGa_2S_4:Dy^{3+}$ at 4.31 μm . T is the total mirror transmission (HR + OC)
- 4) Findlay-Clay plot of absorbed energy threshold vs. total mirror transmission. A round-trip passive loss of L = 0.9 % is deduced from the data.
- 5) Emission spectrum and laser output near 4.3 μ m in CaGa₂S₄:Dy³⁺. When purged with nitrogen, the laser operates at the peak (4.31 μ m) of the fluorescence spectrum. When unpurged, the added loss due to ambient CO₂ absorption forces the laser to operate at a longer wavelength (4.38 μ m).

Figure 1

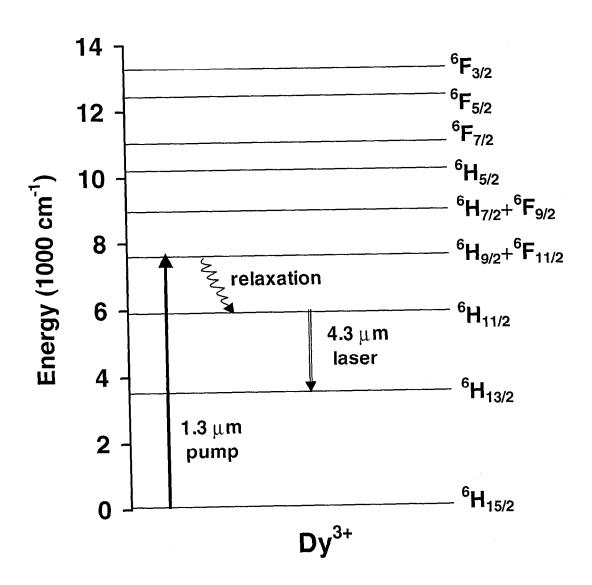


Figure 2

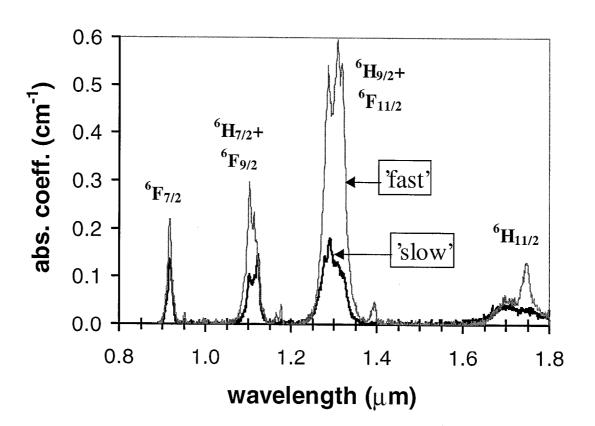


Figure 3

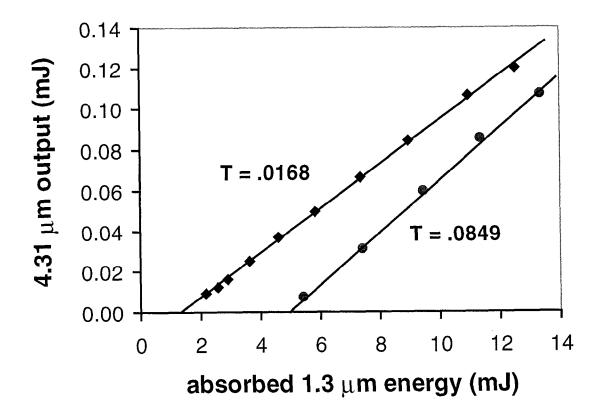


Figure 4

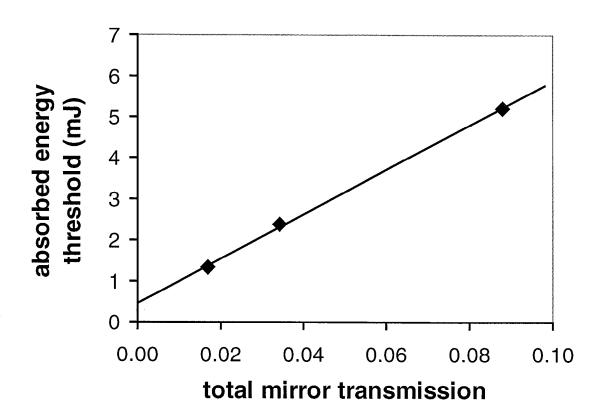
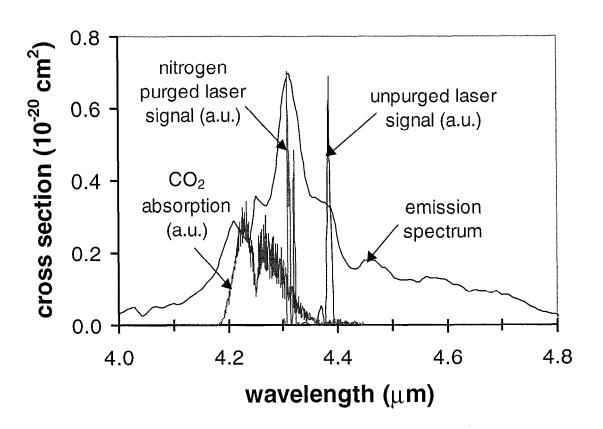


Figure 5



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